

Development of an HV-CMOS active pixel sensor "AstroPix" for all-sky medium-energy gamma-ray telescopes

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All-sky medium-energy gamma-ray observations are essential to deepen our understanding of physics in extreme astronomical objects such as gamma-ray bursts and active galactic nuclei. Those observations are also highly needed to further develop multi-messenger astronomy. Next-generation all-sky MeV gamma-ray telescopes must have a large area detector and keep high sensitivities even in the energies in which Compton scattering is dominant. Having both a silicon tracker (scatterer) and a calorimeter (absorber) as the main detector is a promising configuration for such a space mission. In order to fulfill the requirements such as a large sensitive area, low noise, high energy/positional resolution, and low power, we have been developing an HV-CMOS active pixel sensor, AstroPix. In this contribution, we report performance evaluations of AstroPix such as I-V and noise, energy calibration/resolution/threshold, and depletion depth measurements. Current achievements as a sensor for next-generation all-sky MeV gamma-ray telescopes and future development will be discussed.

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n-well. The signal is processed on the pixel through a charge sensitive amplifier and comparator for the pixel-level trigger ("hit"). Finally the time-over-thresholds (ToTs) from all the hit pixels are digitized in the periphery of the chip. Therefore, both the power consumption and noise (thanks to on-chip signal-processing and digitization) in AstroPix are expected to be low and a high capability of gamma-ray detection (thanks to a large depletion volume) can be achieved.

The requirements for AstroPix to be adopted by AMEGO-X are listed in Table 1. The first version of AstroPix (V1) chip is $725\ \mu\text{m}$ thick and contains 18×18 pixels whose pixel pitch is $175 \times 175\ \mu\text{m}^2$. It was used to understand the sensor and to develop the data acquisition (DAQ) tools. The power consumption is $14.7\ \text{mW}/\text{cm}^2$ and the emission lines from radioisotopes ranging from 14 keV to 122 keV can be found in the analog data [4]. However, the digital data readout is not available due to a flaw in the chip design.

Table 1: Requirements for AstroPix

Pixel pitch (μm^2)	500×500	Dynamic range (keV)	25 - 700
Thickness (μm)	500	Energy resolution (keV)	5 (1σ)
Power consumption (mW/cm^2)	1.5		

The AstroPix V2 chip is $725\ \mu\text{m}$ thick and contains 35×35 pixels whose pixel pitch is $250 \times 250\ \mu\text{m}^2$. The most important upgrade from V1 is the capability of recording the digital data, it is now possible to readout ToT value from each pixel over the chip. The analog data can be read only from the first row pixels. The power consumption is $3.4\ \text{mW}/\text{cm}^2$.

3. Performance of AstroPix V2

In this section, we report results from V2 chips from a $(300 \pm 100)\ \Omega \cdot \text{cm}$ resistivity wafer. The nominal operating bias voltage is $-160\ \text{V}$ supplied by KEITHLEY 2450 SourceMeter.

3.1 I-V curve and typical waveform

The bias voltage dependence of the current draw in a V2 chip was measured by KEITHLEY 2450 SourceMeter as shown in Fig. 2. The breakdown was observed when the bias voltage reached at around $-190\ \text{V}$.

Fig. 3 shows a typical waveform outputted from the charge sensitive amplifier in an analog pixel when irradiated by ^{109}Cd (22.2 keV), which was measured by an oscilloscope (LeCroy T3DSO2302).

3.2 Energy spectra and calibration

By accumulating waveforms with various radioisotopes, the energy spectra in pulse height were measured as shown in Fig. 4. The emission lines ranging from 13.9 keV to (122.1 - 136.5) keV and the Compton edge corresponding to (122.1 - 136.5) keV photons can be found. Fig. 5 shows the correlation between the true energies and the measured pulse heights, showing a good linearity up to $\sim 80\ \text{keV}$ where the analog output starts to saturate due to the saturation in the output buffer for analog data.

Energy spectra in ToT (digital output) are shown in Fig. 6. Because of the limitation of the ToT counter bits, the ToT value of $20.48\ \mu\text{s}$ is the upper edge of the dynamic range in the current

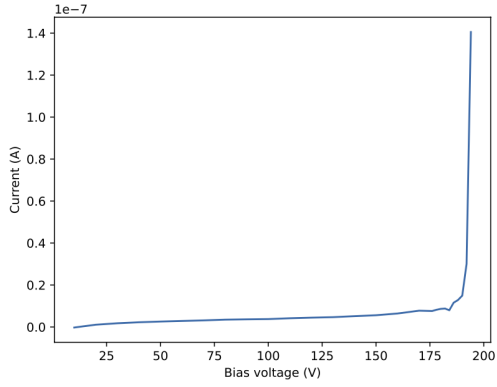


Figure 2: I-V curve. The breakdown voltage is around -190 V.

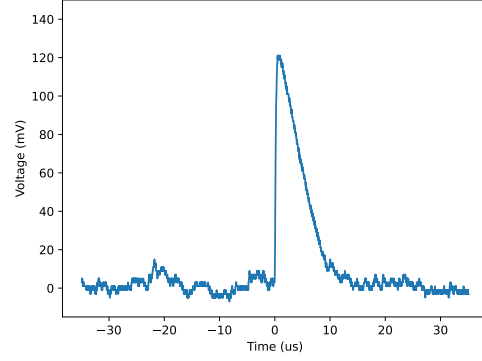


Figure 3: Typical waveform from a pixel when irradiated by ^{109}Cd .

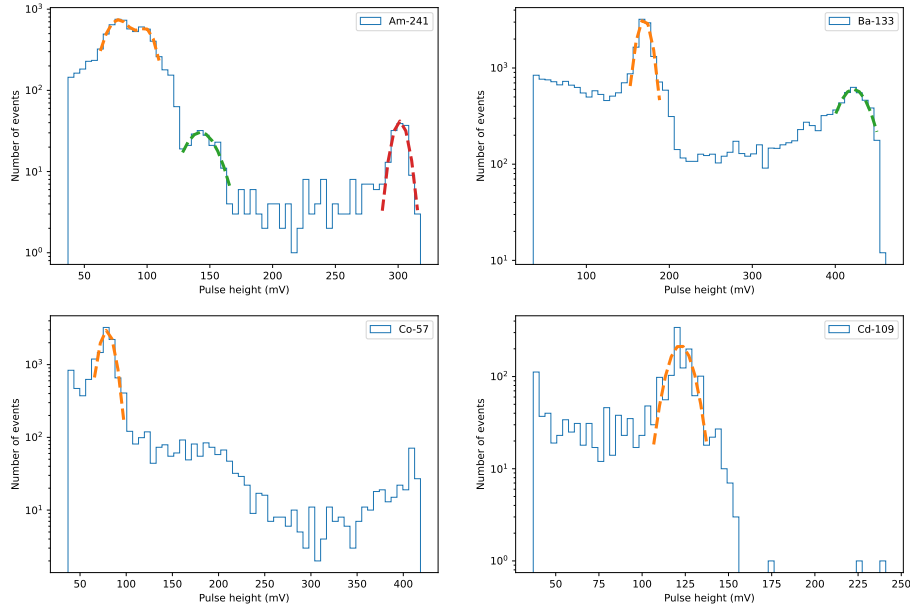


Figure 4: Energy spectra in pulse height from a pixel. *Top left:* ^{241}Am (the photopeaks of 13.9 keV and 17.8 keV fitted with a double Gaussian in orange, 26.3 keV fitted with a Gaussian in green, and 59.5 keV fitted with a Gaussian in red). *Top right:* ^{133}Ba (31.0 keV in orange and 81.0 keV in green). *Lower left:* ^{57}Co (14.4 keV in orange, the Compton edge around 200 mV, and (122.1 - 136.5) keV around 400 mV). *Lower right:* ^{109}Cd (22.2 keV in orange).

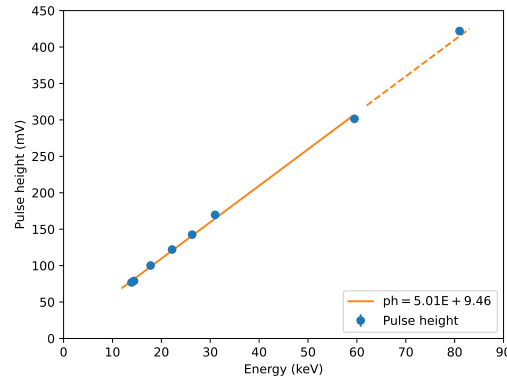


Figure 5: Energy calibration in pulse height for a pixel. The photopeaks from 13.9 keV to 59.5 keV were used to fit by a linear function. The fitted values are shown in the legend. The dotted line is the extrapolation.

configuration. The photopeak of 81.0 keV is visible even though it was affected by the limitation of the ToT counter. Fig. 7 shows the energy calibration in the digital data and the comparison of the energy resolution between the digital and analog data. The linearity can be seen until around ~ 80 keV as well. The energy resolutions in digital are comparable to those in analog and basically satisfy the requirement at least in this pixel.

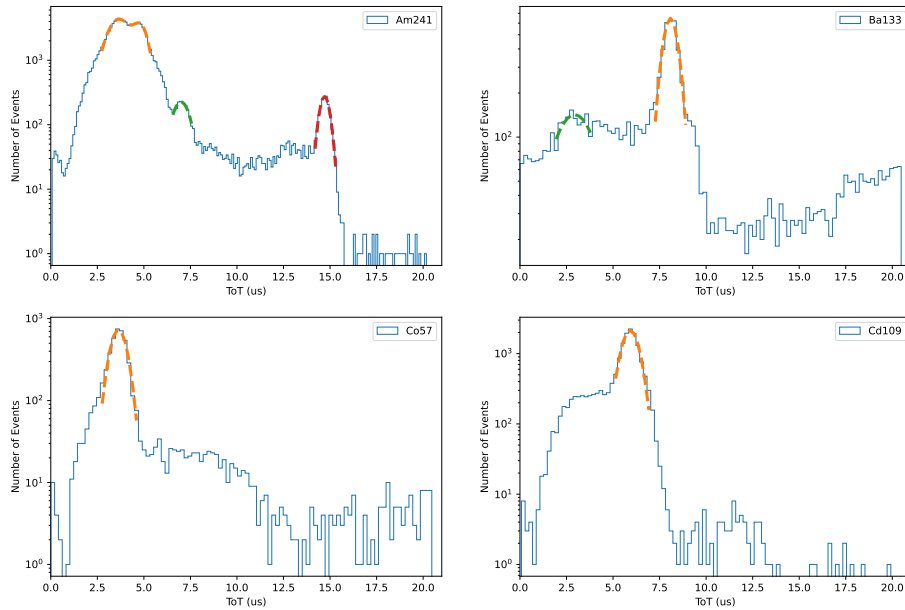


Figure 6: Energy spectra in ToT from a pixel. The notations are the same as in Fig. 4.

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66 3.3 Noise map

67 To evaluate overall noise distribution in the chip, hit rates were measured with various threshold
68 voltages. Only one pixel was enabled to readout the digital data at a time in order to minimize

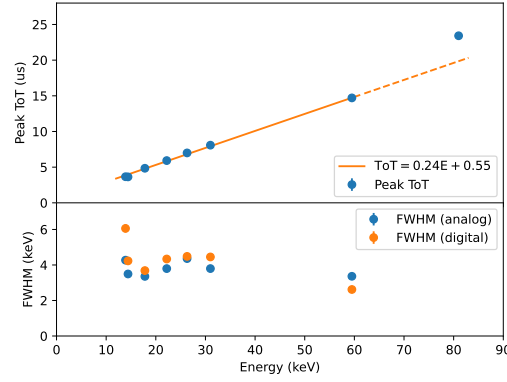


Figure 7: Energy calibration in ToT (*Top panel*) and energy resolutions (FWHM, *Lower panel*) for a pixel. The photopeaks from 13.9 keV to 59.5 keV were used to fit by a linear function. The fitted values are shown in the legend. The dotted line shows the extrapolated line. The FWHM points for analog were evaluated from the data measured by a multi-channel analyzer through a shaping amplifier.

the deadtime. The threshold upper limit is defined as the threshold value at which the rate (= Number of hits/30 sec) becomes zero for the first time by looking from the lowest threshold (25 mV). The resultant noise map and its population are shown in Fig. 8 and 9. The noise level differs from pixel to pixel, but there is no clear pattern or structure over the chip. Assuming there is no gain variation over the sensor, one can use the fitted parameters given in Fig. 5 to estimate the fraction of pixels which satisfy the lower edge of the dynamic range (the corresponding voltage is 135 mV). It is estimated that almost 90% of the pixels satisfy the requirement of 25 keV in the current configuration.

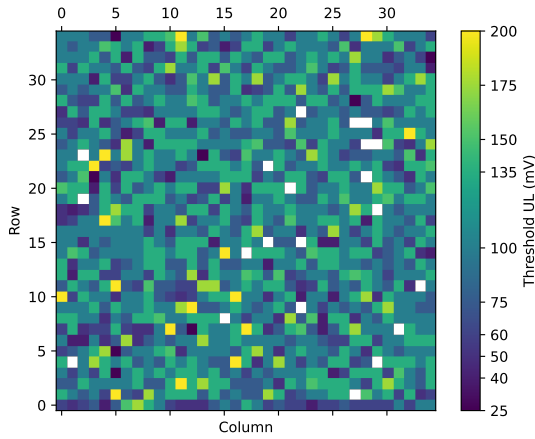


Figure 8: Noise map. The used threshold values are indicated in the color bar. The pixels in white have a larger threshold upper limit than 200 mV.

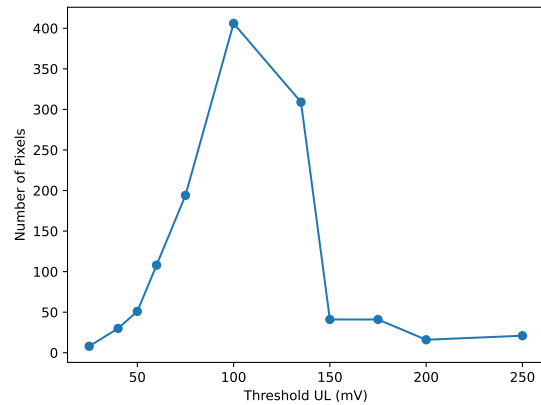


Figure 9: Noise population.

3.4 Depletion depth

The growth of the depletion layer in a pixel was evaluated as follows: 1. Measure the rate of 59.5 keV photons coming from ^{241}Am located at a distance of 3 cm from the chip. 2. Scan the bias voltages and do the step 1 at each stage. 3. Calculate the depletion depth by using the rate, estimated photon intensity, and photoelectric cross section. 4. Compare the data with the simple theoretical PN junction model give by;

$$d = \sqrt{2\epsilon\mu\rho (V_{\text{bias}} + V_{\text{built_in}})} \quad (1)$$

where d is the theoretical depletion depth, ϵ the permittivity, μ the hole mobility, ρ resistivity, V_{bias} the bias voltage, and $V_{\text{built_in}}$ the built-in potential. Fig. 10 shows the growth curve of the depletion layer. Here, however, the data points are scaled to match the model since the detailed evaluation including systematic uncertainties is underway. Nevertheless, the obtained curve seems to follow the model, implying the depletion layer of the V2 chip grows as expected. In order to fully deplete, it is evident that we need to develop chip with a much higher resistivity.

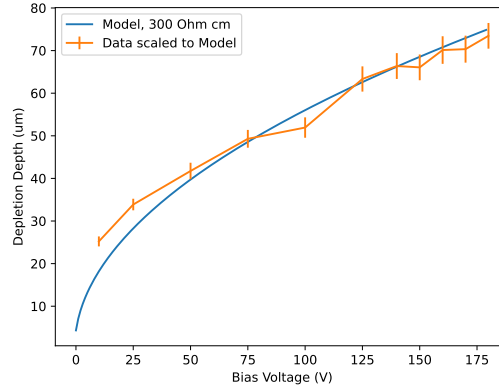


Figure 10: Growth curve of the depletion layer in a pixel. The data points are scaled to match the model.

With the similar setup, but inserting a Copper sheet between ^{241}Am and the sensor to make a single peak ToT distribution by eliminating lower energy photons, the depletion depth of almost all the pixels were evaluated (Fig. 11 and 12). The effective time was calculated by using the waiting time distribution. No clear pattern nor structure are visible and the deviation is 9%.

4. AstroPix V3

The AstroPix V3 chip, the first full reticle chip, is 725 μm thick and contains 35×35 pixels whose pixel pitch is $500 \times 500 \mu\text{m}^2$. While expanding the pixel pitch to the value that is required, the pixel size is kept as small as possible to reduce capacitance. The designed power consumption is 1 mW/cm².

The basic performance evaluation is ongoing. Photopeaks from several radioisotopes were visible even though the noise level seem to get higher due to a larger pixel size compared to that in V2. The gain linearity was also confirmed by using the obtained peaks.

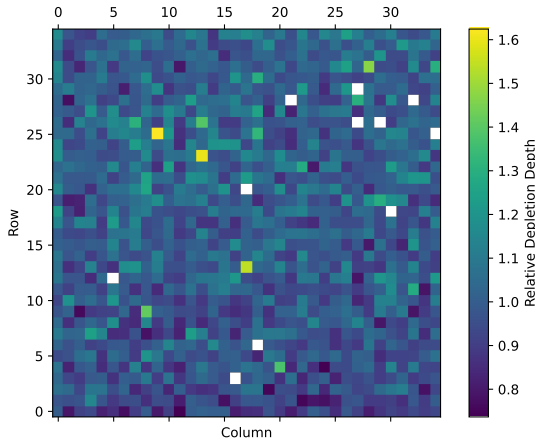


Figure 11: Depletion depth map. The pixels in white were too noisy to measure 59.5 keV photons. The different chip was used from the one in Fig. 8.

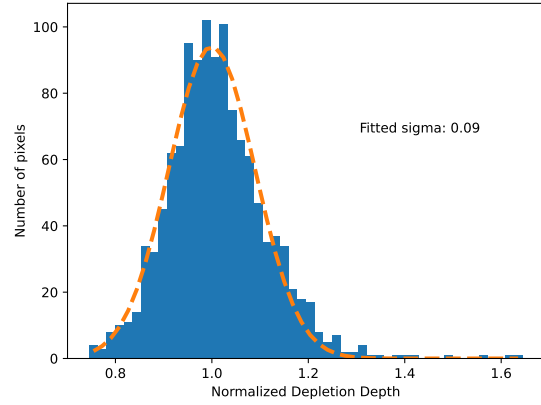


Figure 12: Normalized depletion depth distribution (1D projection of Fig. 11). The dotted line shows a Gaussian fit and the fitted sigma is 0.09.

5. Summary and outlook

Performance of AstroPix V2 was evaluated in both analog and digital. The dynamic range is from 13.9 keV (or less) to 80 keV. The gain linearity is confirmed up to 80 keV. The energy resolution basically satisfies the requirement. The depletion layer grows as expected, but not yet fully depleted. AstroPix V3 was developed to fulfill the requirements of the pixel pitch and the power consumption.

Towards the use of AstroPix in space, “Quad-chip”, a 2×2 array of V3 chips, is in preparation for testing. A Quad-chip will be mounted on a sounding rocket and be operated in space to increase the NASA’s technical readiness level [5].

Acknowledgments

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